Low Voltage Single Supply SPDT Analog Switch

The NLAS4599 is an advanced high speed CMOS single pole – double throw analog switch fabricated with silicon gate CMOS technology. It achieves high speed propagation delays and low ON resistances while maintaining low power dissipation. This switch controls analog and digital voltages that may vary across the full power–supply range (from V_{CC} to GND).

The device has been designed so the ON resistance (R_{ON}) is much lower and more linear over input voltage than R_{ON} of typical CMOS analog switches.

The channel select input is compatible with standard CMOS outputs.

The channel select input structure provides protection when voltages between 0 V and 5.5 V are applied, regardless of the supply voltage. This input structure helps prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

- Channel Select Input Over-Voltage Tolerant to 5.5 V
- Fast Switching and Propagation Speeds
- Break-Before-Make Circuitry
- Low Power Dissipation: $I_{CC} = 2 \mu A$ (Max) at $T_A = 25^{\circ}C$
- Diode Protection Provided on Channel Select Input
- Improved Linearity and Lower ON Resistance over Input Voltage
- Latch-up Performance Exceeds 300 mA
- ESD Performance: Human Body Model > 2000 V; Machine Model > 200 V
- Chip Complexity: 38 FETs
- Pb-Free Packages are Available

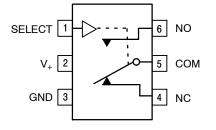


Figure 1. Pin Assignment

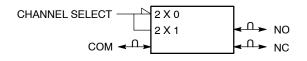


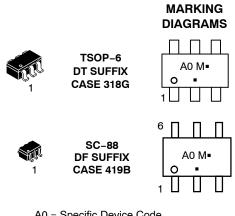
Figure 2. Logic Symbol

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ON Semiconductor®

http://onsemi.com



A0 = Specific Device Code M = Date Code • = Pb-Free Package (Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

FUNCTION TABLE

Select	ON Channel
L	NC
Н	NO

ABSOLUTE MAXIMUM RATINGS

Symbol		Parameter	Value	Unit
V _{CC}	Positive DC Supply Voltage	9	-0.5 to +7.0	V
V _{IS}	Analog Input Voltage (V _{NO}	or V _{COM})	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V _{IN}	Digital Select Input Voltage		$-0.5 \leq V_{l} \leq +\ 7.0$	V
I _{IK}	DC Current, Into or Out of	Any Pin	±50	mA
P _D	Power Dissipation in Still A	ir SC-88 TSOP-6	200 200	mW
T _{STG}	Storage Temperature Rang	-65 to +150	°C	
TL	Lead Temperature, 1mm fr	om Case for 10 seconds	260	°C
TJ	Junction Temperature Und	er Bias	150	°C
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3)	2000 200 N/A	V
I _{LATCH-UP}	Latch-Up Performance	Above V_{CC} and Below GND at 125°C (Note 4)	± 300	mA
θ_{JA}	Thermal Resistance	SC-88 TSOP-6	333 333	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Tested to EIA/JESD22-A114-A

2. Tested to EIA/JESD22-A115-A

3. Tested to JESD22-C101-A

4. Tested to EIA/JESD78

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristic	Min	Max	Unit	
V _{CC}	DC Supply Voltage		2.0	5.5	V
V _{IN}	Digital Select Input Voltage	GND	5.5	V	
V _{IS}	Analog Input Voltage (NC, NO, COM)	GND	V _{CC}	V	
T _A	Operating Temperature Range		-55	+125	°C
t _r , t _f	Input Rise or Fall Time, SELECT	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

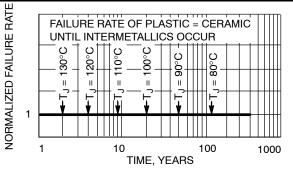


Figure 3. Failure Rate vs. Time Junction Temperature

				Gua			
Symbol	Parameter	Condition	V _{cc}	-55 to 25°C	<85°C	<125°C	Unit
VIH	Minimum High–Level		2.0	1.5	1.5	1.5	V
	Input Voltage, Select		2.5	1.9	1.9	1.9	
	Input		3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			5.5	3.85	3.85	3.85	
V _{IL}	Maximum Low-Level		2.0	0.5	0.5	0.5	V
	Input Voltage, Select		2.5	0.6	0.6	0.6	
	Input		3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			5.5	1.65	1.65	1.65	
I _{IN}	Maximum Input Leakage Current, Select Input	V _{IN} = 5.5 V or GND	5.5	<u>+</u> 0.1	<u>+</u> 1.0	<u>+</u> 1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or GND	0	±10	±10	±10	μΑ
I _{CC}	Maximum Quiescent Supply Current	Select and $V_{IS} = V_{CC}$ or GND	5.5	1.0	1.0	2.0	μΑ

DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

DC ELECTRICAL CHARACTERISTICS – Analog Section

				Gua	aranteed Lin	nit	
Symbol	Parameter	Condition	V _{CC}	–55 to 25°C	<85°C	<125°C	Unit
R _{ON}	Maximum "ON"	V _{IN} = V _{IL} or V _{IH}	2.5	85	95	105	Ω
	Resistance	$V_{IS} = GND$ to V_{CC}	3.0	45	50	55	
	(Figures 17 – 23)	l _{IN} I <u>≤</u> 10.0 mA	4.5	30	35	40	
			5.5	25	30	35	
R _{FLAT} (ON)	ON Resistance Flatness (Figures 17 – 23)	$\label{eq:VIN} \begin{split} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ I_{IN} I &\leq 10.0 \text{ mA} \\ V_{IS} &= 1V, 2V, 3.5V \end{split}$	4.5	4	4	5	Ω
ΔR _{ON} (ON)	ON Resistance Match Between Channels	$\label{eq:VIN} \begin{split} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ I_{IN}I &\leq 10.0 \text{ mA} \\ V_{NO} \text{ or } V_{NC} &= 3.5 \text{ V} \end{split}$	4.5	2	2	3	Ω
I _{NC(OFF)} I _{NO(OFF)}	NO or NC Off Leakage Current (Figure 9)		5.5	1	10	100	nA
I _{COM(ON})	COM ON Leakage Current (Figure 9)	$\label{eq:VIN} \begin{split} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ V_{NO} \ 1.0 \ V \text{ or } 4.5 \ V \text{ with } V_{NC} \\ \text{floating or} \\ V_{NO} \ 1.0 \ V \text{ or } 4.5 \ V \text{ with } V_{NO} \\ \text{floating} \\ V_{COM} &= 1.0 \ V \text{ or } 4.5 \ V \end{split}$	5.5	1	10	100	nA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

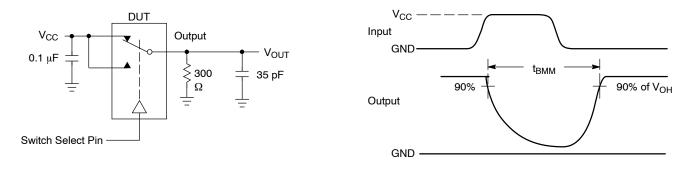
					Guaranteed Max Limit			t				
			v_{cc}	VIS	-5	i5 to 25	°C	<85	5°C	<125°C		
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Max	Min	Max	Unit
t _{ON}	Turn-On Time (Figures 12 and 13)	R_L = 300 Ω,C_L = 35 pF (Figures 5 and 6)	2.5 3.0 4.5 5.5	2.0 2.0 3.0 3.0	5 5 2 2	23 16 11 9	28 21 16 14	5 5 2 2	30 25 20 20	5 5 2 2	30 25 20 20	ns
t _{OFF}	Turn-Off Time (Figures 12 and 13)	R_L = 300 Ω,C_L = 35 pF (Figures 5 and 6)	2.5 3.0 4.5 5.5	2.0 2.0 3.0 3.0	1 1 1 1	7 5 4 3	12 10 9 8	1 1 1 1	15 15 12 12	1 1 1 1	15 15 12 12	ns
t _{BBM}	Minimum Break-Before-Make Time	V_{IS} = 3.0 V (Figure 4) R _L = 300 Ω , C _L = 35 pF	2.5 3.0 4.5 5.5	2.0 2.0 3.0 3.0	1 1 1	12 11 6 5		1 1 1		1 1 1 1		ns

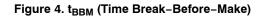
*Typical Characteristics are at 25°C.

		Typical @ 25, VCC = 5.0 V	
$\begin{array}{c} C_{IN} \\ C_{NO} \text{ or } C_{NC} \\ C_{COM} \\ C_{(ON)} \end{array}$	Maximum Input Capacitance, Select Input Analog I/O (switch off) Common I/O (switch off) Feedthrough (switch on)	8 10 10 20	pF

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			v _{cc}	Typical	
Symbol	Parameter	Condition	(Ň)	25°C	Unit
BW	Maximum On–Channel –3dB Bandwidth or Minimum Frequency Response (Figure 10)	$V_{IN} = 0 \text{ dBm}$ V_{IN} centered between V_{CC} and GND (Figure 7)	3.0 4.5 5.5	170 200 200	MHz
V _{ONL}	Maximum Feedthrough On Loss	V_{IN} = 0 dBm @ 100 kHz to 50 MHz V_{IN} centered between V_{CC} and GND (Figure 7)	3.0 4.5 5.5	-3 -3 -3	dB
V _{ISO}	Off-Channel Isolation (Figure 10)	f = 100 kHz; V_{IS} = 1 V RMS V_{IN} centered between V_{CC} and GND (Figure 7)	3.0 4.5 5.5	-93 -93 -93	dB
Q	Charge Injection Select Input to Common I/O (Figure 15)	$ \begin{array}{l} V_{IN} = V_{CC \ to} \ GND, \ F_{IS} = 20 \ \text{kHz} \\ t_r = t_f = 3 \ \text{ns} \\ R_{IS} = 0 \ \Omega, \ C_L = 1000 \ \text{pF} \\ Q = C_L \ast \Delta V_{OUT} \\ (Figure \ 8) \end{array} $	3.0 5.5	1.5 3.0	рC
THD	Total Harmonic Distortion THD + Noise (Figure 14)	F_{IS} = 20 Hz to 100 kHz, R_L = Rgen = 600 $\Omega,$ C_L = 50 pF V_{IS} = 5.0 V_{PP} sine wave	5.5	0.1	%





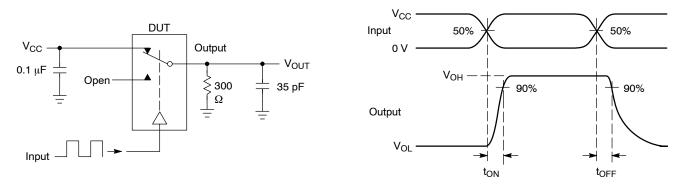
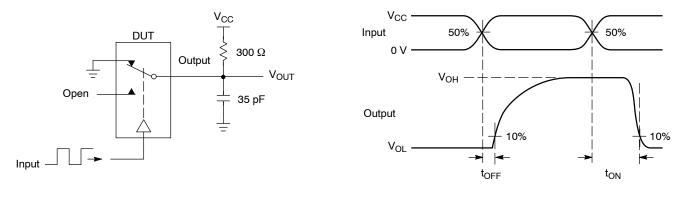
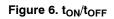
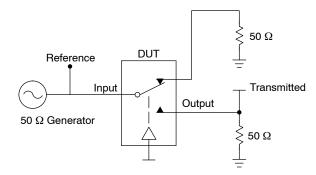


Figure 5. t_{ON}/t_{OFF}



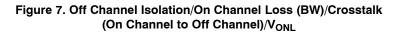


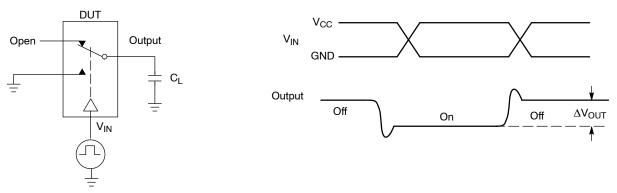


Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO} , Bandwidth and V_{ONL} are independent of the input signal direction.

$$\begin{split} V_{ISO} &= \text{Off Channel Isolation} = 20 \text{ Log } \left(\frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \\ V_{ONL} &= \text{On Channel Loss} = 20 \text{ Log } \left(\frac{V_{OUT}}{V_{IN}} \right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \text{ to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below V_{ONL}







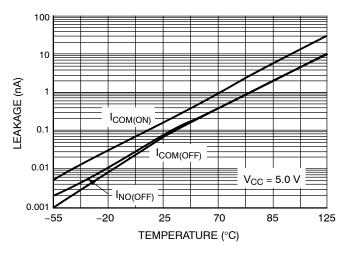
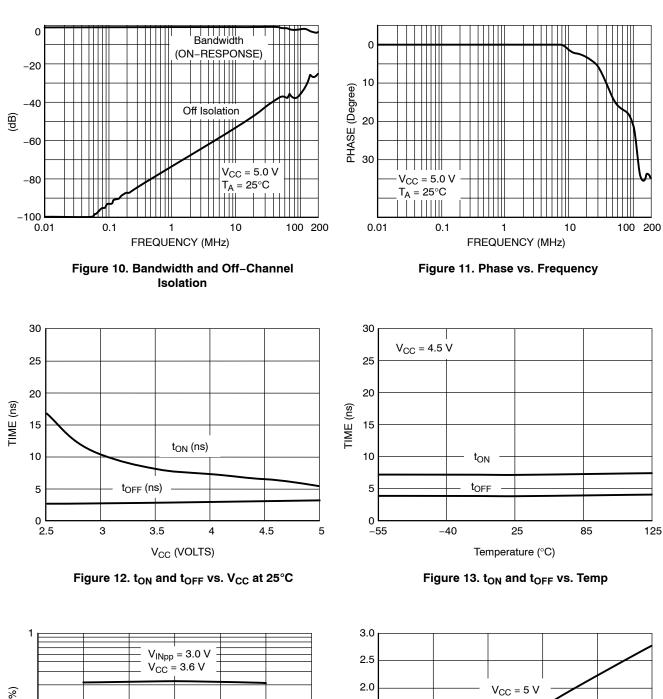
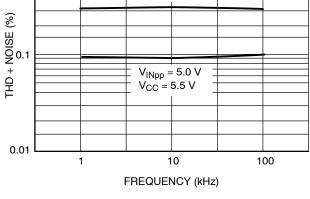
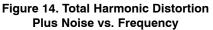
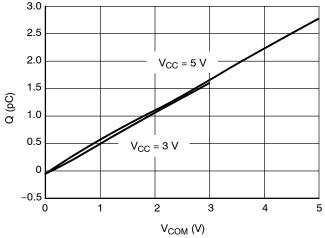


Figure 9. Switch Leakage vs. Temperature

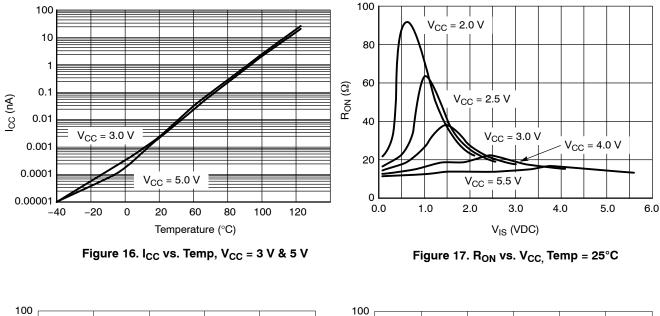


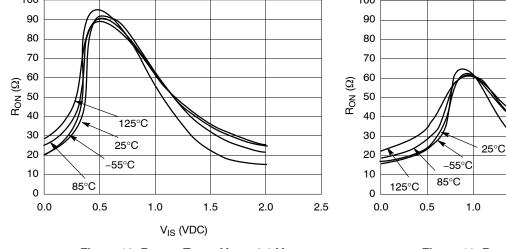














50

45

40 35

30

25

20

15

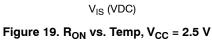
10

5

0

0.0

Ron (Q)

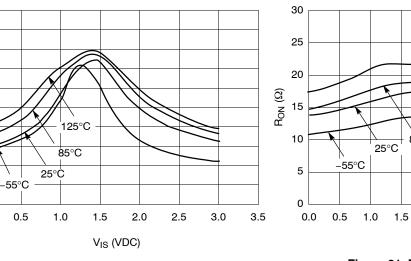


1.5

2.0

2.5

3.0



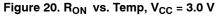


Figure 21. R_{ON} vs. Temp, V_{CC} = 4.5 V

V_{IS} (VDC)

125°C

2.5

3.0

3.5

4.0

4.5

85°C

2.0

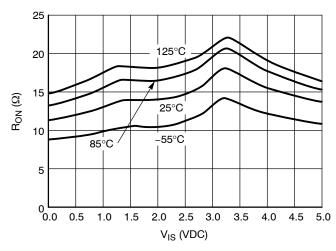


Figure 22. R_{ON} vs. Temp, V_{CC} = 5.0 V

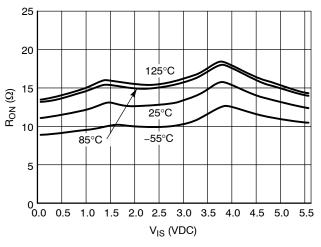


Figure 23. R_{ON} vs. Temp, V_{CC} = 5.5 V

ORDERING INFORMATION

		Device Nom	nenclature			
Device	Circuit Indicator	Technology	Device Function	Suffix	Package	Shipping [†]
NLAS4599DFT2	NL	AS	DF	T2	SC-88	3000 / Tape & Reel
NLAS4599DFT2G	NL	AS	DF	T2G	SC-88 (Pb-Free)	3000 / Tape & Reel
NLAS4599DTT1	NL	AS	DT	T1	TSOP-6	3000 / Tape & Reel
NLAS4599DTT1G	NL	AS	DT	T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel
NLVAS4599DFT2	NL	AS	DF	T2	SC-88	3000 / Tape & Reel
NLVAS4599DFT2G	NL	AS	DF	T2G	SC-88 (Pb-Free)	3000 / Tape & Reel
NLVAS4599DTT1G	NL	AS	DT	T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





98ASB14888C	Electronic versions are uncontrolled except when accessed directly from the Document Reposite Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
TSOP-6		PAGE 1 OF 1			
	98ASB14888C TSOP-6	98ASB14888C Printed versions are uncontrolled except when stamped "CONTROLLED			

ON Semiconductor and use trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights for dhers.

0.043

0.004





- XXX = Specific Device Code

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98ASB42985B Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SC-88/SC70-6/SOT-363 PAGE 1 OF 2 ON Semiconductor and unarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	98ASB42985B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-88/SC70-6/SOT-363		PAGE 2 OF 2
ON Semiconductor and 🕕 are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding			

ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative